

TO 3  
CASE

## 30 Amp Center Tapped Silicon Integrated Rectifiers

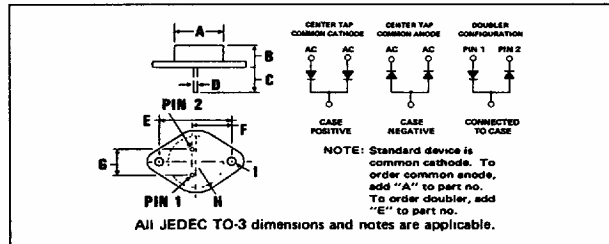
Controlled Avalanche Types with 250V,  
450V, and 650V Minimum Avalanche Ratings

Non-Controlled Avalanche Types with  
100V, 200V, 400V and 600V  $V_{RRM}$  Ratings

High Cycle Surge Current

Fast Recovery Types with 200 Nanosecond Maximum  $t_{rr}$

LTR.	INCHES	MILLIMETERS
A	.73-.77 Dia.	18,54-19,56 Dia.
B	.323-.342	8,20-8,69
C	.40 Min.	10,16
D	.038-.043 Dia.	.97-1,09
E	1.180-1.194	29,97-30,33
F	.665-.675	16,89-17,15
G	.426-.440	10,82-11,18
H	.525R Max.	13,34R
I	.151-.161 Dia.	3,34-4,09



**MAXIMUM RATINGS** (At  $T_A = 25^\circ\text{C}$  unless otherwise noted)

RATINGS	SYMBOL	CONTROLLED AVALANCHE				NON-CONTROLLED AVALANCHE				FAST RECOVERY TIME				UNITS
		R702	R704	R706	R711	R712	R714	R716	R711X	R712X	R714X	R716X		
Series Number														
DC Blocking Voltage	$V_{RM}$	200	400	600	100	200	400	600	100	200	400	600	Volts	
Working Peak Reverse Voltage	$V_{RWM}$													
Peak Repetitive Reverse Voltage	$V_{RRM}$													
RMS Reverse Voltage	$V_{RRMS}$	140	280	420	70	140	280	420	70	140	280	420	Volts	
Power Dissipation in $V_{RRM}$ Region for 100 $\mu$ sec Square Wave (Per diode)	$P_{RM}$	1500				NA				NA				Watts
Continuous Power Dissipation in $V_{RRM}$ Region at $T_C = 100^\circ\text{C}$ (Per diode)	$P_R$	4				NA				NA				Watts
Peak Surge Current, 1/2 Cycle at 60 Hz, (Non-Rep) and $T_C = 100^\circ\text{C}$ (Per diode) (Fig. 2)	$I_{FSM}$	300								150				Amps
Peak Surge Current, 1 sec at 60 Hz and $T_C = 100^\circ\text{C}$ (Per diode) (Fig. 2)	$I_{FRM}$	60								50				Amps
Avg. Forward Current at $T_C = 100^\circ\text{C}$ (Per diode)	$I_O$					15								Amps
Junction Operating and Storage Temperature Range	$T_J, T_{STG}$					- 65 to + 150								$^\circ\text{C}$
Fusing Data	$I^2T$					375				95				Amps <sup>2</sup> -Sec.

**ELECTRICAL CHARACTERISTICS** (At  $T_A = 25^\circ\text{C}$  unless otherwise noted)

CHARACTERISTICS	SYMBOL	CONTROLLED AVALANCHE				NON-CONTROLLED AVALANCHE				FAST RECOVERY TIME				UNITS
		R702	R704	R706	R711	R712	R714	R716	R711X	R712X	R714X	R716X		
Series Number														
Minimum Avalanche Voltage	$V_{BR}$	250	450	650	NA				NA				Volts	
Maximum Avalanche Voltage	$V_{BR}$	700	900	1100	NA				NA				Volts	
Maximum Instantaneous Forward Voltage Drop (Per diode) at 15 Amps (Fig. 3)	$V_{FM}$	1.2								1.4				Volts
Maximum Reverse Current at Rated $V_{RM}$ at $T_C = 100^\circ\text{C}$	$I_{RM}$	1								5				mA
Maximum Reverse Recovery Time at $I_F = 1A, I_R = 2A, I_{RR} = 0.5$ Amp	$t_{rr}$	NA								200				nsec
Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$					1.5								$^\circ\text{C}/\text{W}$

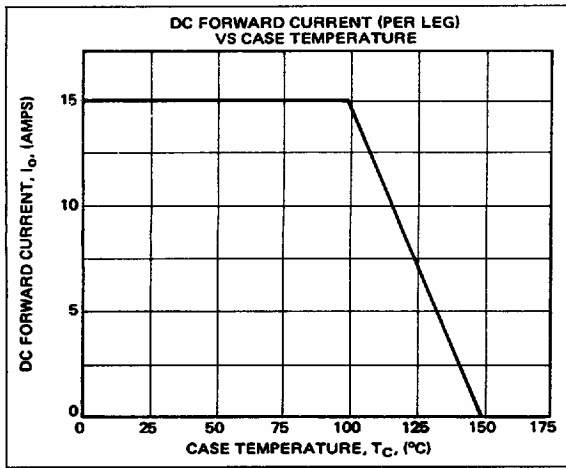


FIGURE 1

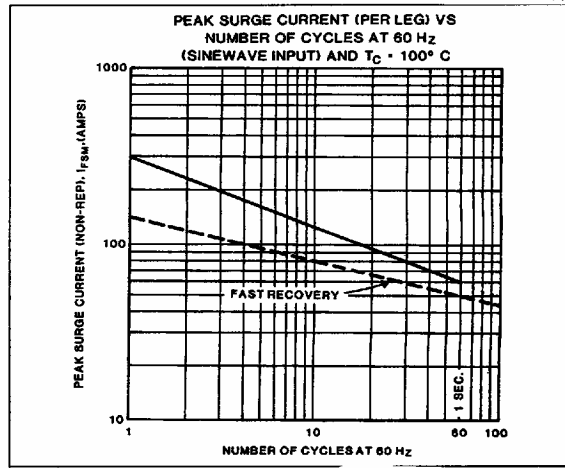


FIGURE 2

T-23-07

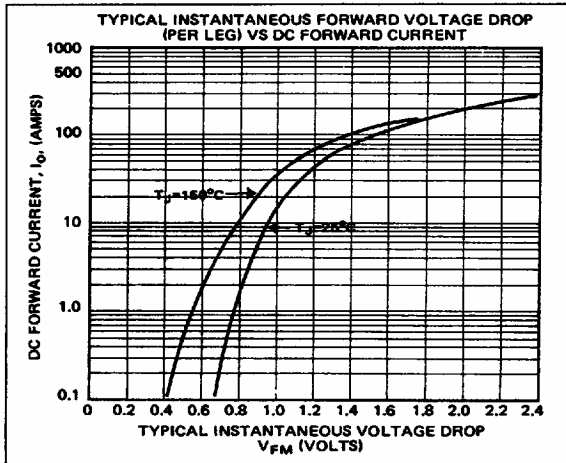


FIGURE 3

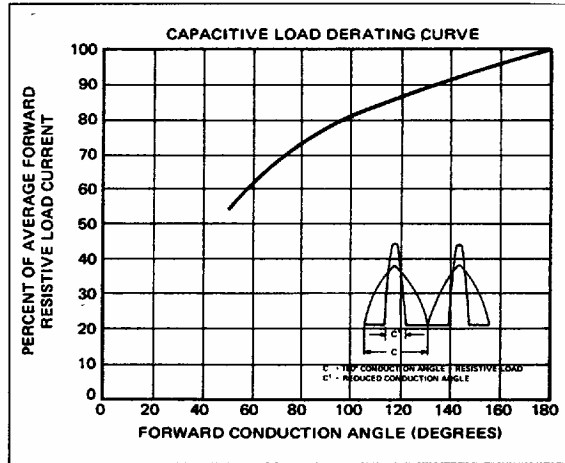


FIGURE 4

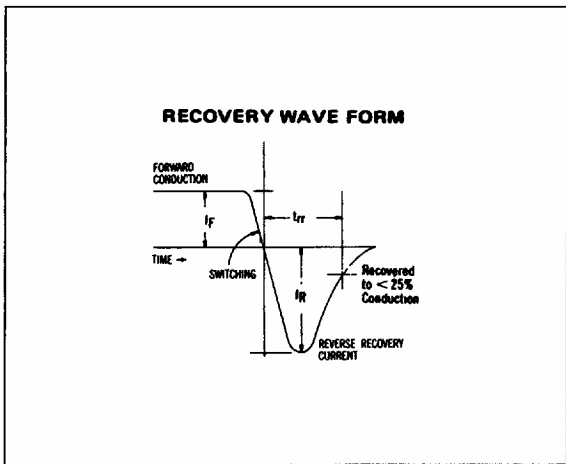


FIGURE 5